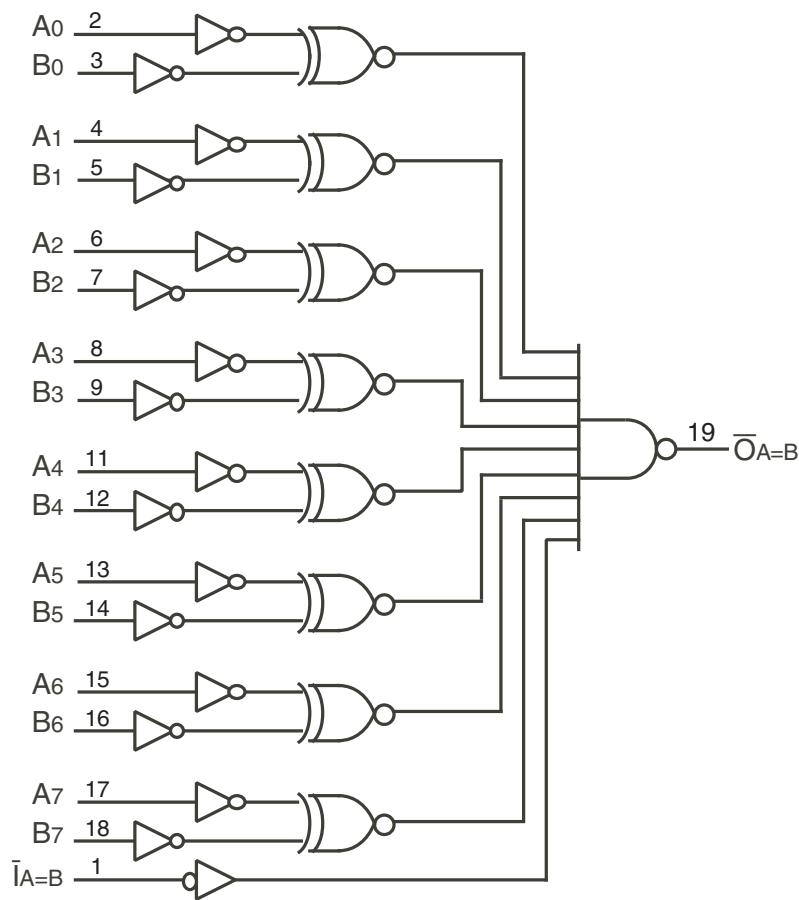


FEATURES:

- A and C grades
- Low input and output leakage $\leq 1\mu\text{A}$ (max.)
- CMOS power levels
- True TTL input and output compatibility:
 - $V_{OH} = 3.3\text{V}$ (typ.)
 - $V_{OL} = 0.3\text{V}$ (typ.)
- High Drive outputs (-15mA I_{OH} , 48mA I_{OL})
- Meets or exceeds JEDEC standard 18 specifications
- Power off disable outputs permit "live insertion"
- Available in SOIC and QSOP packages

DESCRIPTION:

The IDT74FCT521T is an 8-bit identity comparator built using an advanced dual metal CMOS technology. These devices compare two words of up to eight bits each and provide a low output when the two words match bit for bit. The expansion input $\bar{I}_A = B$ also serves as an active low enable input.

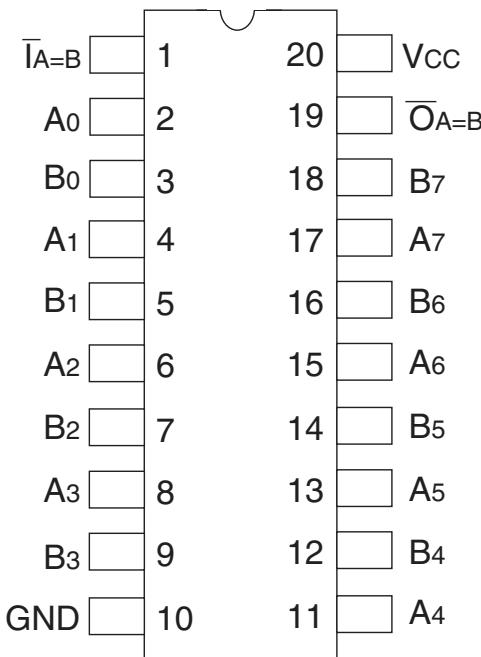
FUNCTIONAL BLOCK DIAGRAM


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INDUSTRIAL TEMPERATURE RANGE

MAY 2018

PIN CONFIGURATION



TOP VIEW

Package Type	Package Code	Order Code
QSOP	PCG20	QG
SOIC	PSG20	SOG

ABSOLUTE MAXIMUM RATINGS⁽¹⁾

Symbol	Description	Max	Unit
VTERM ⁽²⁾	Terminal Voltage with Respect to GND	-0.5 to +7	V
VTERM ⁽³⁾	Terminal Voltage with Respect to GND	-0.5 to V _{CC} +0.5	V
T _{STG}	Storage Temperature	-65 to +150	°C
I _{OUT}	DC Output Current	-60 to +120	mA

NOTES:

- Stresses greater than those listed under ABSOLUTE MAXIMUM RATINGS may cause permanent damage to the device. This is a stress rating only and functional operation of the device at these or any other conditions above those indicated in the operational sections of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect reliability. No terminal voltage may exceed V_{CC} by +0.5V unless otherwise noted.
- Inputs and V_{CC} terminals only.
- Output and I/O terminals only.

CAPACITANCE ($T_A = +25^\circ\text{C}$, $F = 1.0\text{MHz}$)

Symbol	Parameter ⁽¹⁾	Conditions	Typ.	Max.	Unit
C _{IN}	Input Capacitance	V _{IN} = 0V	6	10	pF
C _{OUT}	Output Capacitance	V _{OUT} = 0V	8	12	pF

NOTE:

- This parameter is measured at characterization but not tested.

PIN DESCRIPTION

Pin Names	Description
A ₀ - A ₇	Word A Inputs
B ₀ - B ₇	Word B Inputs
̄A _{=B}	Expansion or Enable Input (Active LOW)
̄O _{A=B}	Identity Output (Active LOW)

FUNCTION TABLE⁽¹⁾

Inputs		Output
̄A _{=B}	A, B	̄O _{A=B}
L	A = B*	L
L	A ≠ B	H
H	A = B*	H
H	A ≠ B	H

NOTE:

- H = HIGH Voltage Level

L = LOW Voltage Level

*A₀ = B₀, A₁ = B₁, A₂ = B₂, etc.

DC ELECTRICAL CHARACTERISTICS OVER OPERATING RANGE

Following Conditions Apply Unless Otherwise Specified:

Industrial: TA = -40°C to +85°C, Vcc = 5.0V ±5%

Symbol	Parameter	Test Conditions ⁽¹⁾		Min.	Typ. ⁽²⁾	Max.	Unit
VIH	Input HIGH Level	Guaranteed Logic HIGH Level		2	—	—	V
VIL	Input LOW Level	Guaranteed Logic LOW Level		—	—	0.8	V
I _{IH}	Input HIGH Current ⁽⁴⁾	Vcc = Max.	VI = 2.7V	—	—	±1	µA
I _{IL}	Input LOW Current ⁽⁴⁾	Vcc = Max.	VI = 0.5V	—	—	±1	
I _I	Input HIGH Current ⁽⁴⁾	Vcc = Max., VI = Vcc (Max.)		—	—	±1	µA
V _{IK}	Clamp Diode Voltage	Vcc = Min., I _{IN} = -18mA		—	-0.7	-1.2	V
I _{OS}	Short Circuit Current	Vcc = Max., VO = GND ⁽³⁾		-60	-120	-225	mA
VOH	Output HIGH Voltage	Vcc = Min	I _{OH} = -8mA	2.4	3.3	—	V
		VI _N = VIH or VIL	I _{OH} = -15mA	2	3	—	
VO _L	Output LOW Voltage	Vcc = Min	I _{OL} = 48mA	—	0.3	0.5	V
VI _H	Input Hysteresis	—		—	200	—	mV
I _{CC}	Quiescent Power Supply Current	Vcc = Max. VI _N = GND or Vcc		—	0.01	1	mA

NOTES:

1. For conditions shown as Min. or Max., use appropriate value specified under Electrical Characteristics for the applicable device type.

2. Typical values are at Vcc = 5.0V, +25°C ambient.

3. Not more than one output should be tested at one time. Duration of the test should not exceed one second.

4. The test limit for this parameter is ±5µA at TA = -55°C.

POWER SUPPLY CHARACTERISTICS

Symbol	Parameter	Test Conditions ⁽¹⁾		Min.	Typ. ⁽²⁾	Max.	Unit
ΔI_{CC}	Quiescent Power Supply Current TTL Inputs HIGH	$V_{CC} = \text{Max.}$ $V_{IN} = 3.4V^{(3)}$		—	0.5	2	mA
I_{CCD}	Dynamic Power Supply Current ⁽⁴⁾	$V_{CC} = \text{Max.}$ Outputs Open One Input Toggling 50% Duty Cycle	$V_{IN} = V_{CC}$ $V_{IN} = GND$	—	0.15	0.25	mA/ MHz
I_C	Total Power Supply Current ⁽⁶⁾	$V_{CC} = \text{Max.}$ Outputs Open $f_i = 10\text{MHz}$ One Bit Toggling 50% Duty Cycle	$V_{IN} = V_{CC}$ $V_{IN} = GND$	—	1.5	3.5	mA
			$V_{IN} = 3.4V$ $V_{IN} = GND$	—	1.8	4.5	

NOTES:

1. For conditions shown as Min. or Max., use appropriate value specified under Electrical Characteristics for the applicable device type.

2. Typical values are at $V_{CC} = 5.0V$, $+25^\circ C$ ambient.

3. Per TTL driven input; ($V_{IN} = 3.4V$). All other inputs at V_{CC} or GND .

4. This parameter is not directly testable, but is derived for use in Total Power Supply Calculations.

5. Values for these conditions are examples of ΔI_{CC} formula. These limits are guaranteed but not tested.

6. $I_C = I_{QUIESCENT} + I_{INPUTS} + I_{DYNAMIC}$

$$I_C = I_{CC} + \Delta I_{CC} D_{HNT} + I_{CCD} (f_{CP}/2 + f_i N_i)$$

I_{CC} = Quiescent Current

ΔI_{CC} = Power Supply Current for a TTL High Input ($V_{IN} = 3.4V$)

D_H = Duty Cycle for TTL Inputs High

N_T = Number of TTL Inputs at D_H

I_{CCD} = Dynamic Current caused by an Input Transition Pair (HLH or LHL)

f_{CP} = Clock Frequency for Register Devices (Zero for Non-Register Devices)

f_i = Output Frequency

N_i = Number of Outputs at f_i

All currents are in millamps and all frequencies are in megahertz.

SWITCHING CHARACTERISTICS OVER OPERATING RANGE

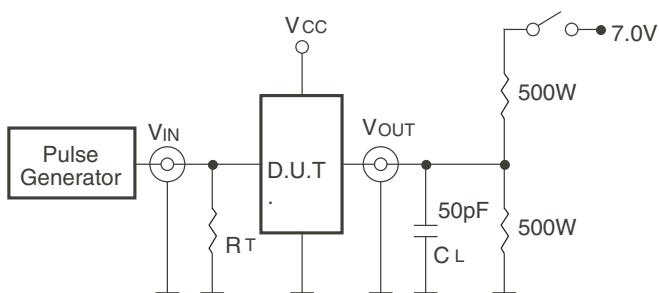
Symbol	Parameter	Condition ⁽¹⁾	74FCT521AT		74FCT521CT		Unit
			Min. ⁽²⁾	Max.	Min. ⁽²⁾	Max.	
t_{PLH}	Propagation Delay A_x or B_x to $\bar{O}_A = B$	$C_L = 50\text{pF}$ $R_L = 500\Omega$	1.5	7.2	1.5	4.5	ns
	Propagation Delay $\bar{I}_A = B$ to $\bar{O}_A = B$		1.5	6	1.5	4.1	

NOTES:

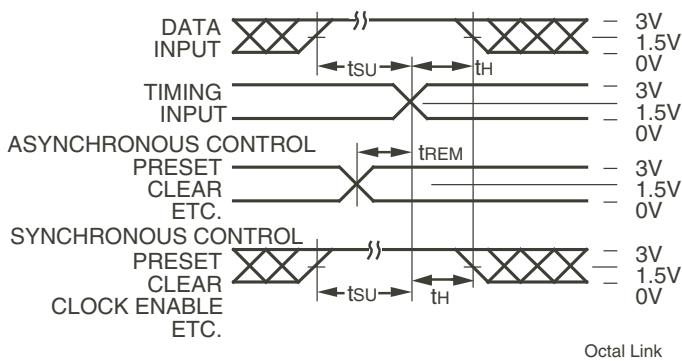
1. See test circuit and waveforms.

2. Minimum limits are guaranteed but not tested on Propagation Delays.

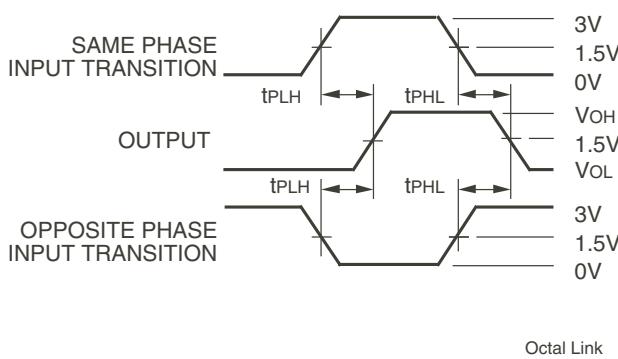
TEST CIRCUITS AND WAVEFORMS



Test Circuits for All Outputs



Set-Up, Hold, and Release Times



Propagation Delay

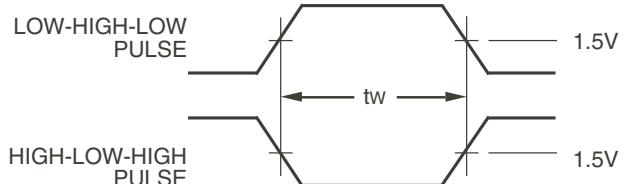
SWITCH POSITION

Test	Switch
Open Drain	Closed
Disable Low	
Enable Low	
All Other Tests	Open

DEFINITIONS:

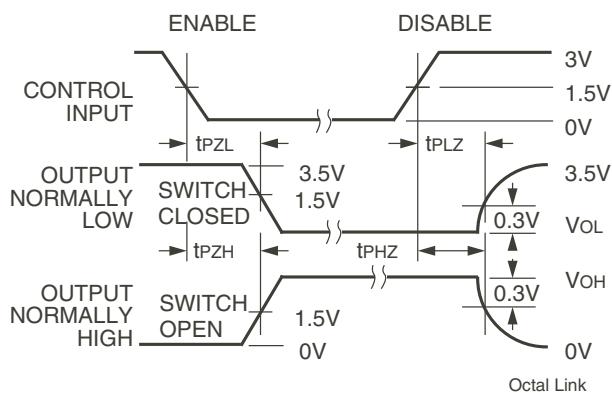
CL = Load capacitance: includes jig and probe capacitance.

R_T = Termination resistance: should be equal to Z_{OUT} of the Pulse Generator.



Pulse Width

Octal Link

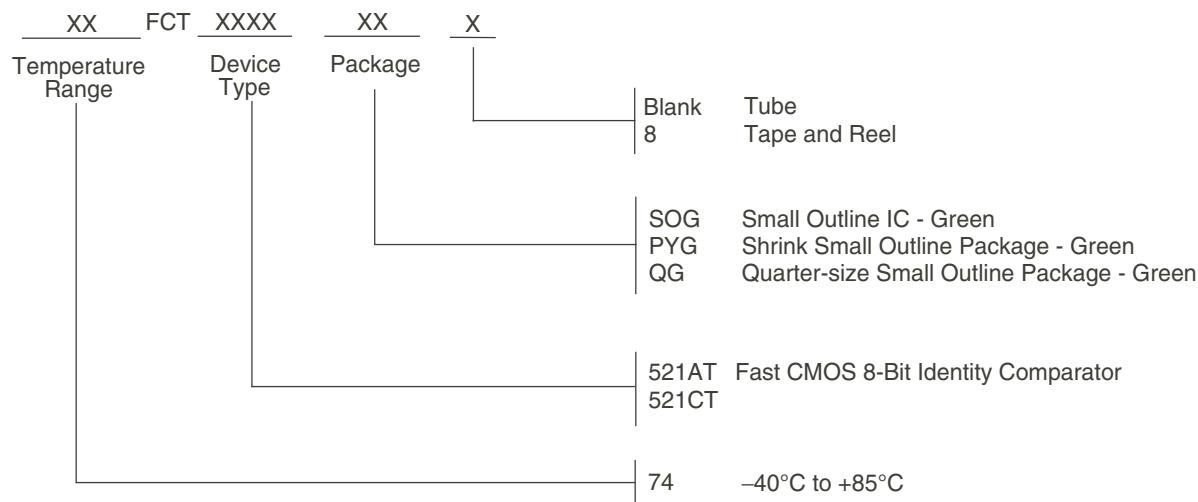


Enable and Disable Times

NOTES:

1. Diagram shown for input Control Enable-LOW and input Control Disable-HIGH.
2. Pulse Generator for All Pulses: Rate \leq 1.0MHz; t_f \leq 2.5ns; t_r \leq 2.5ns.

ORDERING INFORMATION



Orderable Part Information

Speed Grade	Orderable Part ID	Pkg. Code	Pkg. Type	Temp. Grade
A	74FCT521ATQG	PCG20	QSOP	I
	74FCT521ATQG8	PCG20	QSOP	I
	74FCT521ATSOG	PSG20	SOIC	I
	74FCT521ATSOG8	PSG20	SOIC	I
C	74FCT521CTQG	PCG20	QSOP	I
	74FCT521CTQG8	PCG20	QSOP	I
	74FCT521CTSOG	PSG20	SOIC	I
	74FCT521CTSOG8	PSG20	SOIC	I

Datasheet Document History

- 10/03/2009 Pg. 6 Updated the ordering information by removing the "IDT" notation and non RoHS part.
 05/10/2018 Pg. 2, 6 Added table under pin configuration diagram with detailed package information. Updated the ordering information diagram by deleting PYG package and adding Tube, Tape and Reel. Added new table of orderable part information.



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